

PARA LIGHT ELECTRONICS CO., LTD.

11F., No. 8, Jiankang Rd., Zhonghe Dist., New Taipei City 235, Taiwan,Tel: 886-2-2225-3733Fax: 886-2-2225-4800E-mail: para@para.com.twhttp://www.para.com.tw

DATA SHEET

PART NO.: L-S115JFJGCT-U1

REV: <u>A / 1</u>

CUSTOMER'S APPROVAL : DRAWING NO. : DS-78-17-004 DCC :

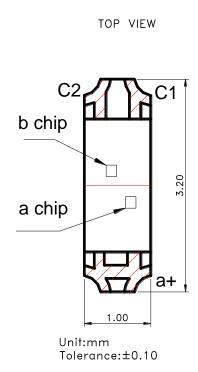
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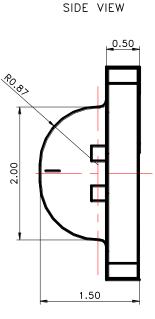


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PACKAGE OUTLINE DIMENSIONS





C1 0.40 CATHODE C2 0.40 0.40 a-

BACK VIEW

C2- C1a+ POLARITY

Notes:

1. a chip: Super Amber; b chip: Super Green.

2. All dimensions are in millimeters.

3. Tolerance is \pm 0.1mm (.004") unless otherwise noted.

Features •

- * Dual color, common anode, side view Chip LED.
- * Package in 8mm tape on 7" diameter reels.
- * Compatible with automatic Pick & Place equipment.
- * Compatible with Reflow soldering and Wave soldering processes.
- * EIA STD package.
- * I.C. compatible.
- * Pb free product.
- * Meet RoHS Green Product.
- * Moisture sensitivity level: 3

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• Chip Materials

chip	Light Color	Dice Material	Lens Color	
a	JF: Super Amber		Water Clear	
b	JG: Super Green	AlInGaP		

• Absolute Maximum Ratings(Ta=25°C)

Symbol	Parameter	Rat	Unit	
Symbol	Falanielei	Super Amber	Super Green	Unit
PD	Power Dissipation	75	60	mW
IPF	Peak Forward Current	80	60	mA
IPF	(1/10 Duty Cycle, 0.1ms Pulse Width)	00	60	
IF	Continuous Forward Current	30	30	mA
VR	Reverse Voltage	5	5	V
ESD	Electrostatic Discharge Threshold(HBM) ^{Note A}	20	00	V
Topr	Operating Temperature Range -40 ~ +85		°C	
Tstg	g Storage Temperature Range -40 ~ +85		°C	

Note A:

HBM: Human Body Model. Seller gives no other assurances regarding the ability of to withstand ESD

• Electro-Optical Characteristics(Ta=25°C)

Parameter		Symbol	Super Amber	Super Green	Unit	Test Condition
	Min.		71	18		
Luminous Intensity	Тур.	IV	112	28	mcd	IF=20mA
	Max.		180	45		
Viewing Angle	Тур.	2 θ 1/2	130		deg	Note 2
	Min.		600	567		
Dominant Wavelength	Тур.	λd	605	570	nm	IF=20mA
	Max.		610	576		
Spectral Line Half-Width	Тур.	Δλ	17	15	nm	
	Min.		1.8	1.8		
Forward Voltage	Тур.	VF	2.0	2.0	V	IF =20mA
	Max.		2.4	2.4		
Reverse Current	Max.	IR	10		μA	VR = 5V
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• Bin Code List

Luminous Intensity(IV), Unit:mcd@20mA					
Super Amber (a chip)			Super Green(b chip)		
Bin Code	Min	Max	Bin Code	Min	Max
Q	71	112	М	18	28
R	112	180	Ν	28	45

Tolerance of each bin are $\pm 15\%$

Dominant Wavelength (Hue), Unit: nm@20mA			
Super Green (b chip)			
Bin Code	Min	Max	
GA	567	570	
GB	570	573	
GC	573	576	

Tolerance of each bin are ± 1 nm

Notes:

- 1. Luminous intensity is measured with a light sensor and filter combination that proximities the CIE eye-response curve.
- 2. $\theta_{1/2}$ is the off-axis angle at which the luminous intensity is half the axial luminous intensity.
- 3. The dominant wavelength λd is derived from the CIE chromaticity diagram and represents the single wavelength which defines the color of the device.
- 4. Caution in ESD :

Static Electricity and surge damages the LED. It is recommended use a wrist band or anti-electrostatic glove when handling the LED. All devices, equipment and machinery must be properly grounded.

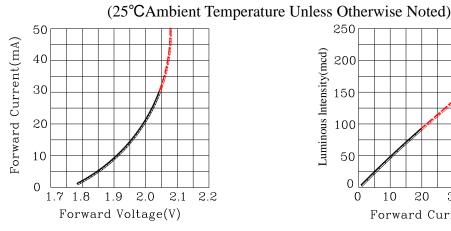
5. Major standard testing equipment by "Instrument System" Model : CAS140B Compact Array Spectrometer and "KEITHLEY" Source Meter Model : 2400.

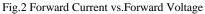


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Super Amber Typical Electro-Optical Characteristics Curves





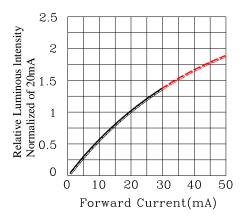
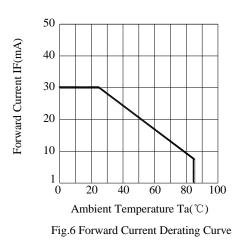


Fig.4 Relative Luminous Intensity vs.Forward Current



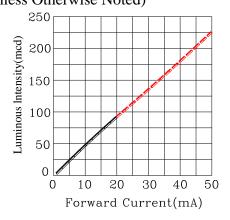


Fig.3 Luminous Intensity vs.Forward Current

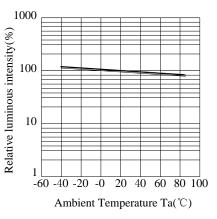


Fig.5 Luminous Intensity vs.Ambient Temperature

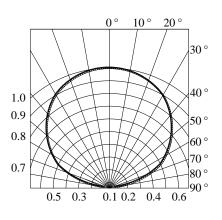


Fig.7 Relative Intensity vs.Angle

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• Super Green Typical Electro-Optical Characteristics Curves

(25°CAmbient Temperature Unless Otherwise Noted)

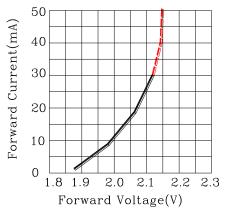


Fig.2 Forward Current vs.Forward Voltage

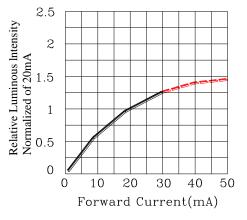


Fig.4 Relative Luminous Intensity vs.Forward Current

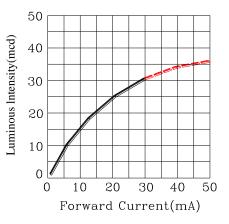


Fig.3 Luminous Intensity vs.Forward Current

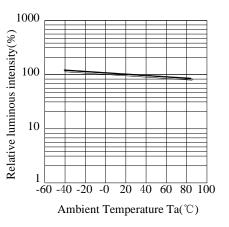
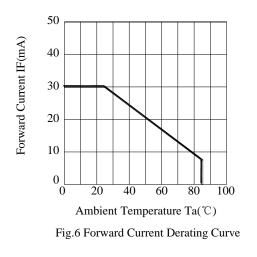


Fig.5 Luminous Intensity vs.Ambient Temperature



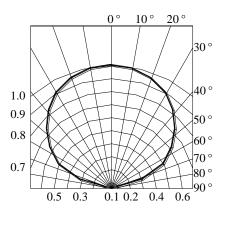


Fig.7 Relative Intensity vs.Angle

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• Label Explanation



ITEM CODE:PARA LIGHT

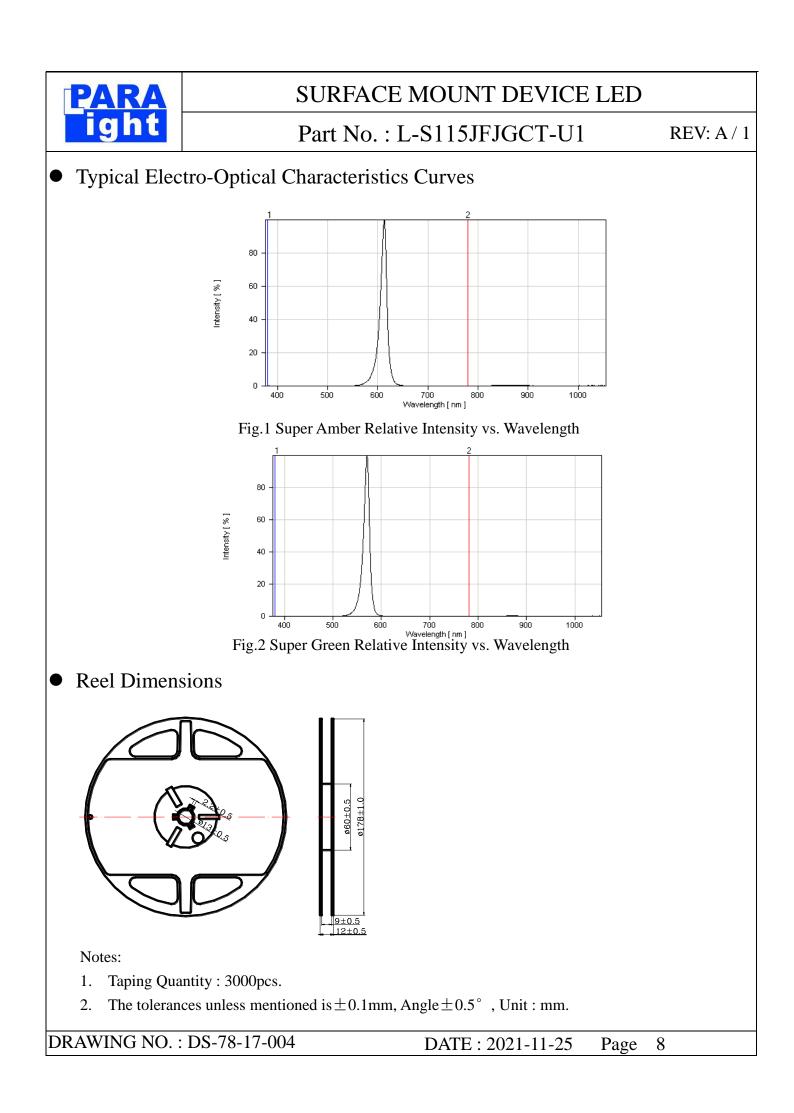
PART NO: L-S115JFJGCT IV --- Luminous Intensity Code

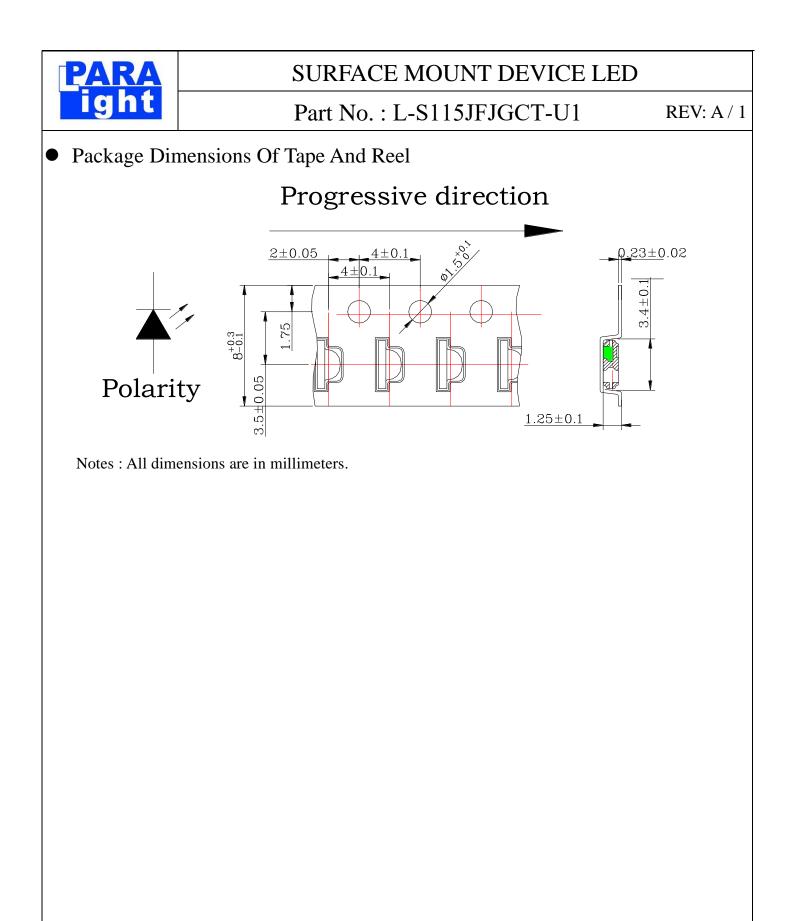
LOT NO: EM S 09 0110 L 12 В Е Α С D F A---EM: Emos Code B---S:SMD C---Local D---Year E---Month F---SPEC. PACKING QUANTITY OF BAG: 3000pcs for 150, 170, 110, 155, 115 series 4000pcs for 191 series 5000pcs for 192 series DATE CODE: <u>2012</u> <u>09</u> 10 G Η Ι

G---- Year H---- Month

I --- Day

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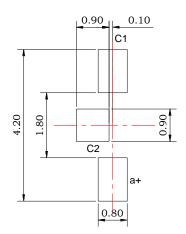
Part No. : L-S115JFJGCT-U1

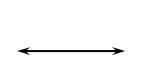
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Cleaning

- * If cleaning is required, use the following solutions for less than 1 minute and less than 40° C.
- * Appropriate chemicals: Ethyl alcohol and isopropyl alcohol.
- Effect of ultrasonic cleaning on the LED resin body differs depending on such factors as the oscillator output, size of PCB and LED mounting method. The use of ultrasonic cleaning should be enforced at proper output after confirming there is no problem.

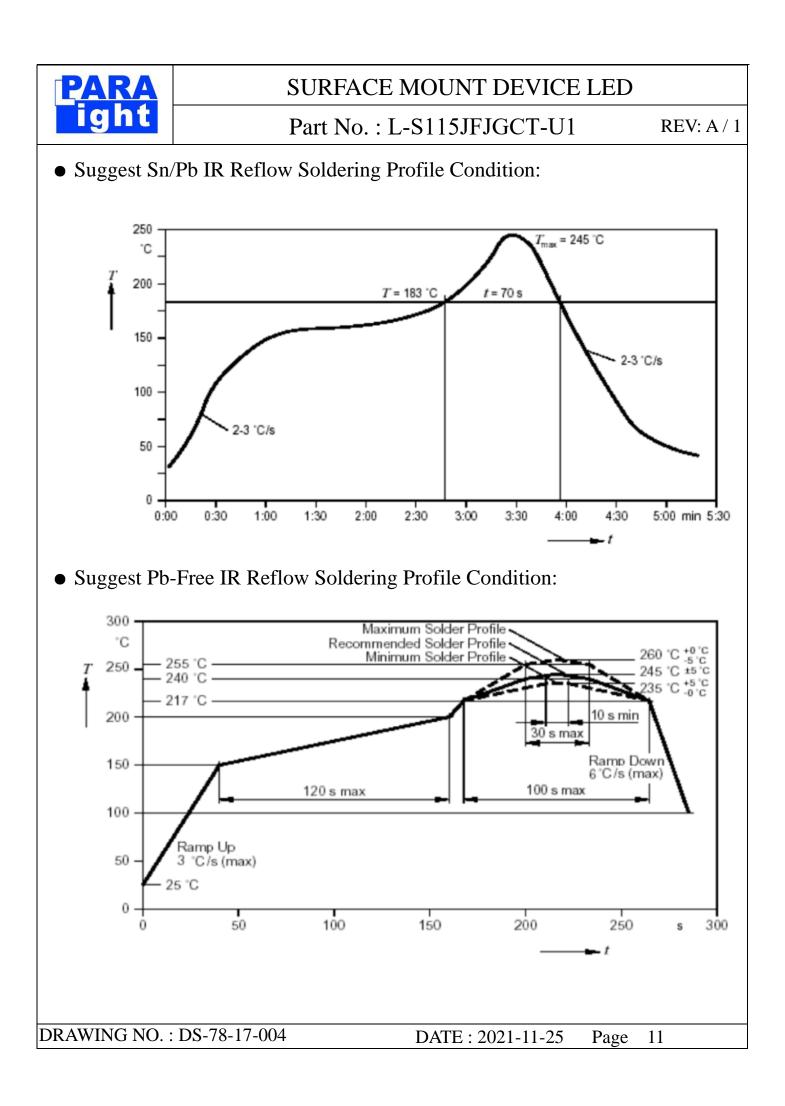
Suggest Soldering Pad Dimensions





Direction of PWB camber and go to reflow furnace

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• CAUTIONS

1. Application Limitation :

The LED's described here are intended to be used for ordinary electronic equipment (such as office equipment, communication equipment and household application).Consult PARA's sales in advance for information on application in which exceptional quality and reliability are required, particularly when the failure or malfunction of the LED's may directly jeopardize life or health (such as airplanes, automobiles, traffic control equipment, life support system and safety devices).

2.Storage :

Do not open moisture proof bag before the products are ready to use.

Before opening the package: The LEDs should be kept at 30° C or less and 90%RH or less.

If the moisture absorbent material (silica gel) has faded away or the LEDs have exceeded the storage time, baking treatment should be performed using the following conditions.

Baking treatment: 60 ± 5 °C for 24 hours.

3.Soldering(Standard Process) :

Do not apply any stress to the lead frame during soldering while the LED is at high temperature. Recommended soldering condition.

Reflow Soldering :

Pre-heat 120~150 °C, 120sec. MAX., Peak temperature : 240 °C Max. Soldering time : 10 sec Max. Soldering Iron : (Not recommended)

Temperature 300 $^{\circ}$ C Max., Soldering time : 3 sec. Max.(one time only), power dissipation of iron : 20W Max. use SN60 solder of solder with silver content and don't to touch LED lens when soldering. Wave soldering :

Pre-heat 100 $^{\circ}$ C Max, Pre-heat time 60s Max, Solder wave 260 $^{\circ}$ C Max, Soldering time 5 sec. Max. preformed consecutively cooling process is required between 1st and 2nd soldering processes.



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4. Lead-Free Soldering

For Reflow Soldering :

- 1、Pre-Heat Temp: 150-180°C,120sec.Max.
- 2. Soldering Temp : Temperature Of Soldering Pot Over 230°C,40sec.Max.
- 3, Peak Temperature : 260° C, 5sec.
- 4、Reflow Repetition: 2 Times Max.
- 5、 Suggest Solder Paste Formula 93.3 Sn/3.1 Ag/3.1 Bi /0.5 Cu

For Soldering Iron (Not Recommended) :

- 1, Iron Tip Temp : 350° C Max.
- 2、Soldering Iron: 30w Max.
- 3、Soldering Time : 3 Sec. Max. One Time.

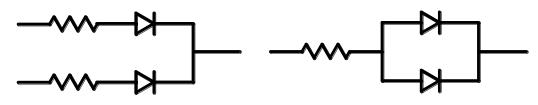
For Dip Soldering :

- 2. Bath Temp : 265° C Max.
- 3、Dip Time : 5 Sec. Max.

5. Drive Method

Circuit model A

Circuit model B



(A)Recommended circuit.

(B)The difference of brightness between LED's could be found due to the Vf-If characteristics of LED.